

# Photonic-organic Electrochemical Transistor

**A light-driven transistor offering low-energy, crosstalk-resistant signaling for neuromorphic sensors and artificial-retina systems.**

Researchers at Purdue University have developed a photonic-organic electrochemical transistor (POECT). This device uses the 3-terminal layout of a conventional transistor (source, drain, gate), but uses light rather than electricity as the means of signal transmission enabling significantly faster transmission while mitigating crosstalk. Test results from a prototype POECT demonstrated continuously programmable conductance states and low writing energy. Applications of this technology will allow for the creation of systems that emulate biological synapse functions or artificial retinas.

## Advantages:

- Ultra-fast signal transmission
- Limited crosstalk between transistors
- Continuously programmable conductance states
- Low writing energy

## Applications:

- Biosensors
- Synaptic devices for biological applications
- Neuromorphic computing
- Emulation of biological elements (artificial retina)

## Technology Validation:

This technology has been validated with lab-scale fabrication and testing of the proposed device.

Related Publications:

## Technology ID

2023-MEI-70196

## Category

Computing/Photonic & Optical  
Computing Technologies  
Medtech & Digital  
Health/Implantable Medical  
Devices  
Chemicals & Advanced  
Materials/Materials Processing &  
Manufacturing Technologies

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## View online



Ke Chen et al, Organic optoelectronic synapse based on photon-modulated electrochemical doping, Nature Photonics (2023). DOI: 10.1038/s41566-023-01232-x

<https://techxplore.com/news/2023-11-human-eye-boost-vision-efficiency.html>

**TRL: 5**

**Intellectual Property:**

Provisional-Patent, 2023-03-09, United States | PCT-Patent, 2024-03-07, WO  
| NATL-Patent, 2025-06-26, United States